NSR0240H

Schottky Barrier Diode

Schottky barrier diodes are optimized for very low forward voltage drop and low leakage current and are used in a wide range of dc-dc converter, clamping and protection applications in portable devices. NSR0240H in a SOD-323 miniature package enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

Features

- Very Low Forward Voltage Drop –480 mV @ 100 mA
- Low Reverse Current 0.2 µA @ 25 V VR
- 250 mA of Continuous Forward Current
- Power Dissipation of 160 mW with Minimum Trace
- Very High Switching Speed
- Low Capacitance CT = 4 pF
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- LCD and Keypad Backlighting
- Camera Photo Flash
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

Markets

- Mobile Handsets
- MP3 Players
- Digital Camera and Camcorders
- Notebook PCs and PDAs
- GPS

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	40	Vdc
Forward Continuous Current (DC)	IF	250	mA
Non-Repetitive Peak Forward Surge Current	I _{FSM}	1.0	А
ESD Rating: Human Body Model Machine Model	ESD	Class 1B Class A	

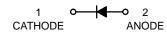
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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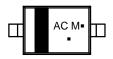
40 VOLT SCHOTTKY BARRIER DIODE



MARKING DIAGRAM



SOD-323 CASE 477 STYLE 1



AC = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NSR0240HT1G	SOD-323 (Pb-Free)	3000 / Tape & Reel
NSVR0240HT1G	SOD-323 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

THERMAL CHARACTERISTICS

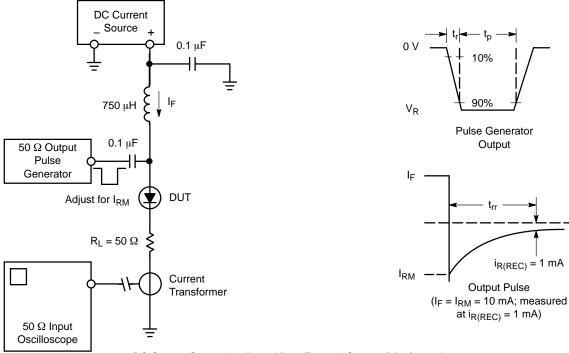
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction–to–Ambient (Note 1) Total Power Dissipation @ T _A = 25°C	R _{θJA}	740	°C/W
	P _D	160	mW
Thermal Resistance Junction–to–Ambient (Note 2) Total Power Dissipation @ T _A = 25°C	R _{θJA}	460	°C/W
	P _D	270	mW
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

- 1. Mounted onto a 4 in square FR-4 board 10 mm sq. 1 oz. Cu 0.06" thick single-sided. Operating to steady state.
- 2. Mounted onto a 4 in square FR-4 board 1 in sq. 1 oz. Cu 0.06" thick single-sided. Operating to steady state.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Leakage $(V_R = 10 \text{ V})$ $(V_R = 25 \text{ V})$ $(V_R = 40 \text{ V})$	I _R		0.2 0.6	0.55 2.0 10	μΑ
Forward Voltage (I _F = 10 mA) (I _F = 100 mA) (I _F = 200 mA)	V _F		345 480 585	450 550 710	mV
Total Capacitance (V _R = 5.0 V, f = 1 MHz)	СТ		4.0		pF
Reverse Recovery Time $(I_F = I_R = 10 \text{ mA}, I_R = 1.0 \text{ mA})$	t _{rr}		3.0		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



- 1. DC Current Source is adjusted for a Forward Current (I_F) of 10 mA.
- 2. Pulse Generator Output is adjusted for a Peak Reverse Recovery Current I_{RM} of 10 mA.
- 3. Pulse Generator transition time $<< t_{rr}$.
- 4. IR(REC) is measured at 1 mA. Typically 0.1 X I_{RM} or 0.25 X I_{RM}.
- 5. $t_p * t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

NSR0240H

TYPICAL CHARACTERISTICS

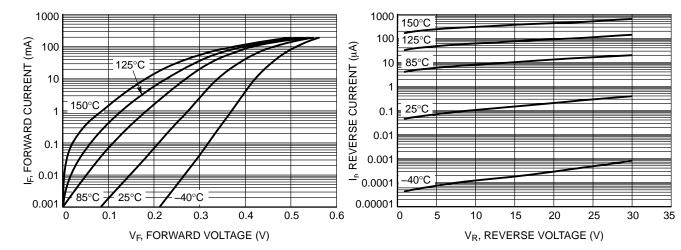


Figure 2. Forward Voltage

Figure 3. Leakage Current

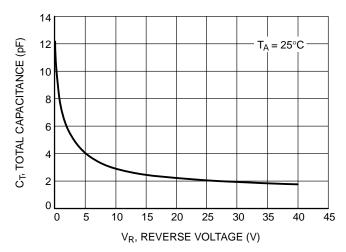
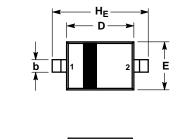


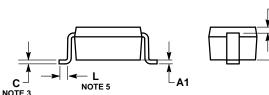
Figure 4. Total Capacitance

NSR0240H

PACKAGE DIMENSIONS

SOD-323 CASE 477-02 **ISSUE H**





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
- CONTROLLING DIMENSION: MILLIMETERS. LEAD THICKNESS SPECIFIED PER L/F DRAWING
- WITH SOLDER PLATING.

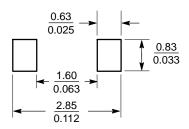
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

 5. DIMENSION L IS MEASURED FROM END OF RADIUS.

		MILLIMETERS			INCHES		
DI	М	MIN	NOM	MAX	MIN	NOM	MAX
Α	١.	0.80	0.90	1.00	0.031	0.035	0.040
Α	1	0.00	0.05	0.10	0.000	0.002	0.004
A	3	0.15 REF			0.006 REF		
b	,	0.25	0.32	0.4	0.010	0.012	0.016
С	``	0.089	0.12	0.177	0.003	0.005	0.007
D	(1.60	1.70	1.80	0.062	0.066	0.070
E		1.15	1.25	1.35	0.045	0.049	0.053
L	. [0.08			0.003		
H	Е	2.30	2.50	2.70	0.090	0.098	0.105

PIN 1. CATHODE 2. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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